

U74LVC1G79

CMOS IC

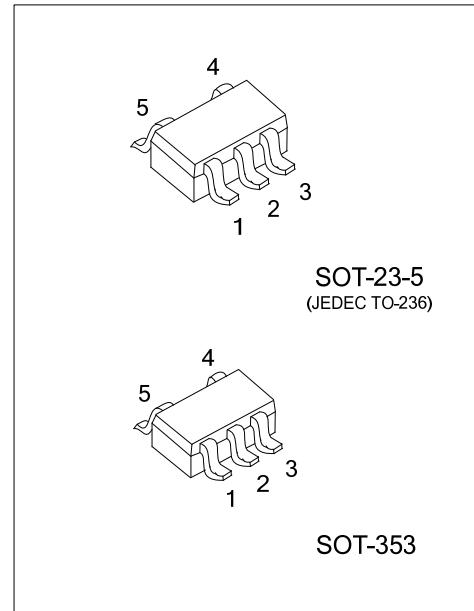
SINGLE POSITIVE-EDGE-TRIGGERED D-TYPE FLIP-FLOP

■ DESCRIPTION

The **U74LVC1G79** is a single positive-edge-triggered D-type flip-flop.

When data at the data input (D) meets the set-up time requirements, the data is transferred to the outputs (Q) on the positive-going edge of the clock pulse. Following the hold-time interval, data at the D input can be changed without affecting the level at the outputs.

This device has power-down protective circuit, preventing device destruction when it is powered down.



■ FEATURES

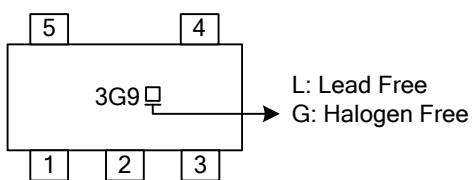
- * Operate from 1.65V to 5.5V
- * Inputs accept voltages to 5.5V
- * I_{off} supports partial-power-down mode
- * Low power dissipation: $I_{CC}=10\mu A$ (Max.)
- * $\pm 24mA$ output drive($V_{CC}=3.3V$)

■ ORDERING INFORMATION

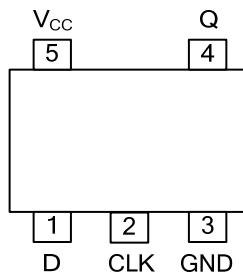
Ordering Number		Package	Packing
Lead Free	Halogen Free		
U74LVC1G79G-AE5-R	U74LVC1G79G-AE5-R	SOT-23-5	Tape Reel
U74LVC1G79G-AL5-R	U74LVC1G79G-AL5-R	SOT-353	Tape Reel

U74LVC1G79G-AE5-R	(1)Packing Type (2)Package Type (3)Green Package	(1) R: Tape Reel (2) AE5: SOT-23-5, AL5: SOT-353 (3) G: Halogen Free and Lead Free, L: Lead Free
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■ MARKING



■ PIN CONFIGURATION



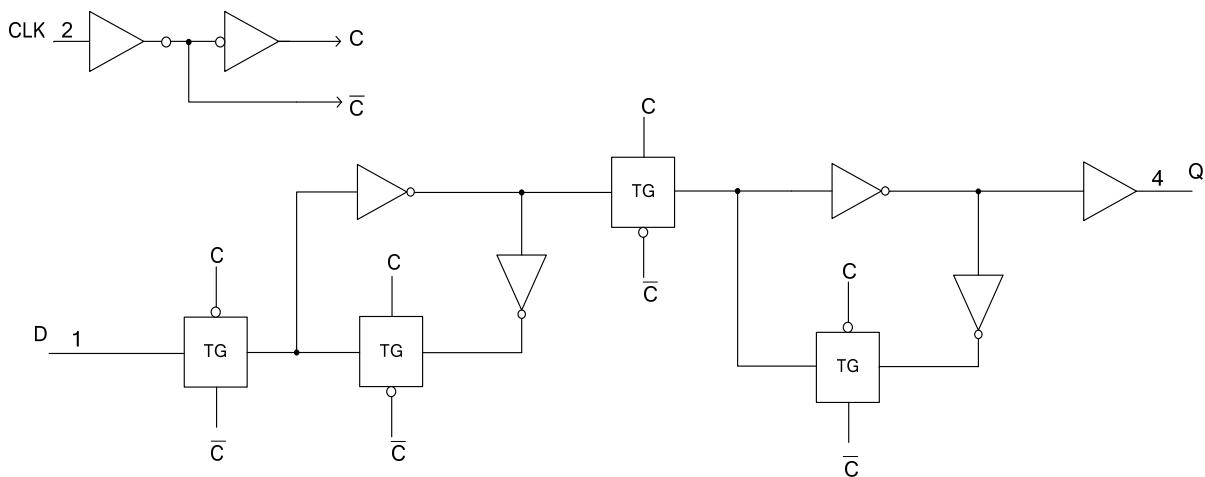
■ FUNCTION TABLE (EACH GATE)

INPUT		OUTPUT
CLK	D	Q
↑	H	H
↑	L	L
L	X	Q ₀

Note: H: HIGH voltage level; L: LOW voltage level; X: Don't care; ↑: Low to High CLK transition

Q₀: indicates the state of referenced input, one set-up time prior to the LOW-to-HIGH CLK transition

■ LOGIC DIAGRAM (positive logic)



■ ABSOLUTE MAXIMUM RATING (Unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Supply Voltage		V _{CC}	-0.5 ~ +6.5	V
Input Voltage		V _{IN}	-0.5 ~ +6.5	V
Output Voltage	Output in the high or low state Output in the high-impedance or power-off state	V _{OUT}	-0.5 ~ V _{CC} +0.5 -0.5 ~ +6.5	V
V _{CC} or GND Current		I _{CC}	±100	mA
Continuous Output Current (V _{OUT} =0 ~ V _{CC})		I _{OUT}	±50	mA
Input Clamp Current (V _{IN} <0)		I _{IK}	-50	mA
Output Clamp Current (V _{OUT} <0)		I _{OK}	-50	mA
Storage Temperature Range		T _{STG}	-65 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	V _{CC}	Operating	1.65		5.5	V
		Data retention only	1.5			V
Input Voltage	V _{IN}		0		5.5	V
Output Voltage	V _{OUT}		0	V _{CC}		V
High-Level Input Voltage	V _{IH}	V _{CC} =1.65V~1.95V	0.65xV _{CC}			V
		V _{CC} =2.3V~2.7V	1.7			
		V _{CC} =3.0V~3.6V	2			
		V _{CC} =4.5V~5.5V	0.7xV _{CC}			
Low-Level Input Voltage	V _{IL}	V _{CC} =1.65V~1.95V		0.35xV _{CC}		V
		V _{CC} =2.3V~2.7V		0.7		
		V _{CC} =3.0V~3.6V		0.8		
		V _{CC} =4.5V~5.5V		0.3xV _{CC}		
High-level Output Current	I _{OH}	V _{CC} =1.65V			-4	mA
		V _{CC} =2.3V			-8	mA
		V _{CC} =3.0V			-16	mA
		V _{CC} =3.0V			-24	mA
		V _{CC} =4.5V			-32	mA
Low-level Output Current	I _{OL}	V _{CC} =1.65V			4	mA
		V _{CC} =2.3V			8	mA
		V _{CC} =3.0V			16	mA
		V _{CC} =3.0V			24	mA
		V _{CC} =4.5V			32	mA
Input Transition Rise or Fall Rate	Δt/Δv	V _{CC} =1.65V~1.95V, 2.3V~2.7V			20	ns/V
		V _{CC} =3.0V~3.6V			10	ns/V
		V _{CC} =4.5V~5.5V			5	ns/V
Operating Temperature	T _A		-40		+125	°C

■ ELECTRICAL CHARACTERISTICS (Unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
High-Level Output Voltage	V_{OH}	$V_{CC}=1.65V \sim 5.5V, I_{OH}=-100\mu A$	$V_{CC}-0.1$			V
		$V_{CC}=1.65V, I_{OH}=-4mA$	1.2			
		$V_{CC}=2.3V, I_{OH}=-8mA$	1.9			
		$V_{CC}=3.0V, I_{OH}=-16mA$	2.4			
		$V_{CC}=3.0V, I_{OH}=-24mA$	2.3			
		$V_{CC}=4.5V, I_{OH}=-32mA$	3.8			
Low-Level Output Voltage	V_{OL}	$V_{CC}=1.65V \sim 5.5V, I_{OL}=-100\mu A$			0.1	V
		$V_{CC}=1.65V, I_{OL}=4mA$			0.45	
		$V_{CC}=2.3V, I_{OL}=8mA$			0.3	
		$V_{CC}=3.0V, I_{OL}=16mA$			0.4	
		$V_{CC}=3.0V, I_{OL}=24mA$			0.55	
		$V_{CC}=4.5V, I_{OL}=32mA$			0.55	
Input Leakage Current	$I_{I(LEAK)}$	$V_{CC}=0V \sim 5.5V, V_{IN}=5.5V$ or GND			± 10	μA
Power OFF Leakage Current	I_{OFF}	$V_{CC}=0V, V_{IN}$ or $V_{OUT}=5.5V$			± 10	μA
Quiescent Supply Current	I_Q	$V_{CC}=1.65V \sim 5.5V, V_{IN}=5.5V$ or GND, $I_{OUT}=0$			10	μA
Additional Quiescent Supply Current	ΔI_Q	$V_{CC}=3V \sim 5.5V$, One input at $V_{CC}-0.6V$, other inputs at V_{CC} or GND			500	μA
Input Capacitance	C_{IN}	$V_{CC}=3.3V, V_{IN}=V_{CC}$ or GND		4		pF

■ DYNAMIC CHARACTERISTICS (Unless otherwise specified)

PARAMETER	SYMBOL	Conditions	MIN	TYP	MAX	UNIT
Clock frequency	f_{CLOCK}				160	MHZ
Pulse duration	t_w	$V_{CC}=1.8V \pm 0.15V$	2.5			ns
		$V_{CC}=2.5V \pm 0.2V$	2.5			
		$V_{CC}=3.3V \pm 0.3V$	2.5			
		$V_{CC}=5V \pm 0.5V$	2.5			
Setup time before CLK ↑	t_{su}	$V_{CC}=1.8V \pm 0.15V$	2.2			ns
		$V_{CC}=2.5V \pm 0.2V$	1.4			
		$V_{CC}=3.3V \pm 0.3V$	1.3			
		$V_{CC}=5V \pm 0.5V$	1.2			
		$V_{CC}=1.8V \pm 0.15V$	2.6			
		$V_{CC}=2.5V \pm 0.2V$	1.4			
		$V_{CC}=3.3V \pm 0.3V$	1.3			
		$V_{CC}=5V \pm 0.5V$	1.2			
Hold time ,data after CLK ↑	t_h	$V_{CC}=1.8V \pm 0.15V$	0.3			ns
		$V_{CC}=2.5V \pm 0.2V$	0.4			
		$V_{CC}=3.3V \pm 0.3V$	1			
		$V_{CC}=5V \pm 0.5V$	0.5			

■ SWITCHING CHARACTERISTIC (Input: $t_R, t_F \leq 2.5\text{ns}$; PRR $\leq 1\text{MHz}$)

See Fig. 1 and Fig. 2 for test circuit and waveforms.

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Maximum clock pulse frequency	f_{MAX}	$V_{CC} = 1.65V \sim 5.5V$	160			MHz
Propagation delay from input (CLK) to output(Q)	t_{PLH}/t_{PHL}	$V_{CC} = 1.65V \sim 1.95V, CL = 15\text{pF}$	2.5		9.1	ns
		$V_{CC} = 2.3V \sim 2.7V, CL = 15\text{pF}$	1.2		6.0	
		$V_{CC} = 3.0V \sim 3.6V, CL = 15\text{pF}$	1.0		4.0	
		$V_{CC} = 4.5V \sim 5.5V, CL = 15\text{pF}$	0.8		3.8	
		$V_{CC} = 1.65V \sim 1.95V, CL = 30\text{pF}$	3.9		9.9	
Propagation delay from input (CLK) to output(Q)	t_{PLH}/t_{PHL}	$V_{CC} = 2.3V \sim 2.7V, CL = 30\text{pF}$	2.0		7.0	ns
		$V_{CC} = 3.0V \sim 3.6V, CL = 50\text{pF}$	1.7		5.0	
		$V_{CC} = 4.5V \sim 5.5V, CL = 50\text{pF}$	1.0		4.5	

■ OPERATING CHARACTERISTICS (Unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Power Dissipation Capacitance	Cpd	$V_{CC} = 3.3V, f = 10\text{MHz}$		27		pF

■ TEST CIRCUIT AND WAVEFORMS

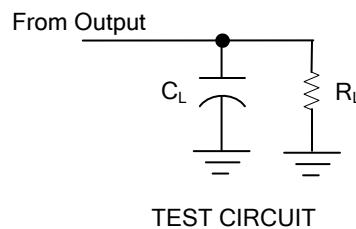


Fig.1 Load circuitry for switching times.

V _{CC}	V _{IN}	t _R /t _F	V _M	C _L	R _L
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	15pF	1MΩ
				30pF	1KΩ
2.5V±0.2V	V _{CC}	≤2ns	V _{CC} /2	15pF	1MΩ
				30pF	500Ω
3.3V±0.3V	3 V	≤2.5ns	1.5V	15pF	1MΩ
				50pF	500Ω
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	15pF	1MΩ
				50pF	500Ω

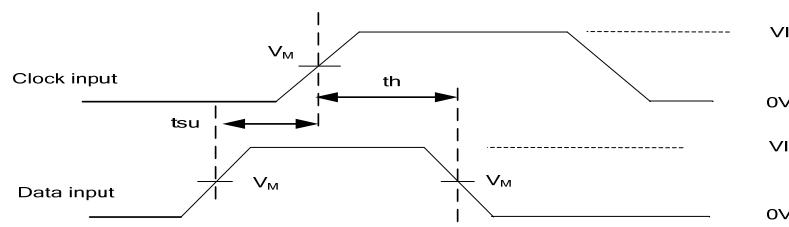
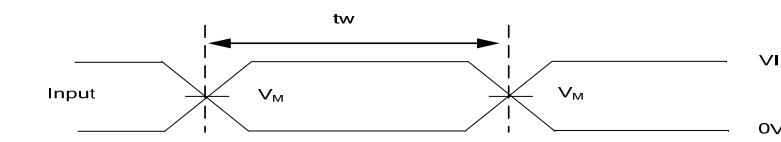
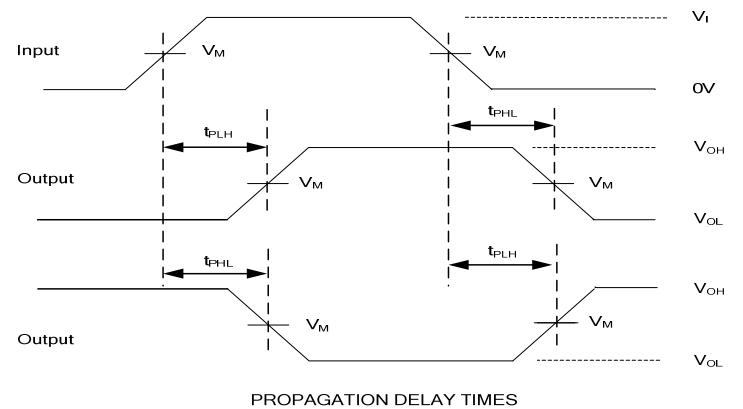


Fig. 2 Propagation delay from input to output and input voltage waveforms.

Notes: 1. C_L includes probe and jig capacitance.

2. All input pulses are supplied by generators having the following characteristics: PRR ≤10MHz, Z_o = 50Ω.

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